

### Introduction of Huawei Smart I-V Curve Diagnosis

Version 1.0 Release Date Feb 16<sup>th</sup>, 2020



Huawei Technologies Co., Ltd.

#### Copyright Huawei Technologies Co., Ltd. 2020. All rights reserved.

No part of this document may be reproduced or transmitted in any form or by any means without the prior written consent of Huawei Technologies Co., Ltd.

#### **Trademark Declaration**

and other Huawei trademarks are trademarks belonging to Huawei Technologies Co., Ltd.

All other trademarks and trade names mentioned in this document are the property of their respective holders.

#### Note:

The purchased products, services and features are stipulated by the contract made between Huawei and the customer. All or part of the products, services and features described in this document may not be within the purchase scope or the usage scope. Unless otherwise specified in the contract, all statements, information, and recommendations in this document are provided without warranties, guarantees, or representations of any kind, either express or implied.

The information in this document is subject to change without notice. Every effort has been made in the preparation of this document to ensure accuracy of the contents, but all statements, information, and recommendations in this document do not constitute the warranty of any kind, express or implied.

#### Huawei Technologies Co., Ltd.

Address:	Huawei Industrial Base Bantian, Longgang, Shenzhen 518129
Website:	http://solar.huawei.com
Email:	support@huawei.com
Customer Service Tel:	0086 4008302118

### History

Date	Version	Description.	Author	Review
2020-02-16	1.00	First version	G00420735/Gu Xin	Z00526139/Zheng Yue Z00400285/Zhang Yan W00316493/Wang Cong P00313221/Peng Te GKAD Tiger Team Region CTOs

### Content

1 Overview	1
2 PV Module	2
2.1 PV Module in the Entire PV System	2
2.2 Fault Types of PV Modules	2
2.3 Introduction of On-site Inspection of PV Modules	4
3 Huawei Smart I-V Curve Diagnosis	6
3.1 Mechanism	6
3.1.1 Mechanism for String I-V Scanning	6
3.1.2 Mechanism for Diagnosis	7
3.2 Solution of Smart I-V Curve Diagnosis	
3.3 Specifications of Smart I-V Curve Diagnosis	9
3.4 Output of Smart I-V Curve Diagnosis	
4 How to Use Smart I-V Curve Diagnosis	12
4.1 Start the Diagnosis and Output the Reports	
4.1.1 Requirements	
4.1.2 Operation	
4.2 Review of Diagnostic Report and Make an Informed O&M Decision	
4.3 Case Study	
5 Value of Smart I-V Curve Diagnosis	
5.1 Secure PV Assets by 100% Inspection	16
5.2 Saving Energy Yield Loss by Protecting PV System from Faults	
5.3 Saving Time and Cost Compared to Other Approaches	
6 Appendix	20

## **1** Overview

With the wide and rapid deployment of PV plants around the world, the industry will step into Terawatt era in the middle of 2020s and more and more attentions have been already paid to the operation of PV plants than the early-stage construction and commission. Failures and faults are the most common issues in the PV plant. Most of them at AC side can be easily confirmed and recovered since the O&M companies have rich experience in thermal power and hydropower that can be transferred to PV O&M. But at DC side it seems to be impossible to inspect and recover the faults and failures. On one hand it is because of the lack of experience of O&M people in the maintenance of DC equipment. On the other hand, it is due to the huge quantity of devices and the lack of DC O&M experience. Therefore, most of faulted or failed modules remained untreated in the PV plant, resulting in the loss of generation energy, the increased risk of safety and hence the high risk of asset and investment.

In the year of 2016, based on the leading technology of string inverter and the understanding of AI technology, Huawei solar business released a revolutionary function, Smart I-V Curve Diagnosis, to help the customers deal with the DC side inspection. Through 4 year online running, Smart I-V Curve Diagnosis has become one of the most powerful tools against difficult O&M and energy loss, which has 5 GW application and was awarded Terawatt Diamond Award, SNEC Top 10 Highest Award.

This document is the introduction of Huawei Smart I-V Curve Diagnosis, aiming to elaborate the failure of PV modules, I-V curve testing, mechanism of Huawei Smart I-V Curve Diagnosis function and the value for customers.

# **2** PV Module

A PV system generally contains PV modules, racks, cables and terminals at DC side, among which PV modules are the main component that generates power and hence have the most important influence on the power loss when failures or faults occur. This section is to introduce the mechanism on how PV modules work, the faults and failures associated with PV modules and the on-site testing methodology.

#### 2.1 PV Module in the Entire PV System

PV module (also called solar panel) is the essential and the most important part of the PV system, a fundamental unit of PV system (or photovoltaic device) that converts solar energy into electrical energy, which is then stored in a storage battery or used to drive loads. In actual PV plant applications, multiple PV modules are connected in series to form a PV string, and then one or more PV strings are connected in parallel to an inverter that converts DC power into AC power.

Like most semiconductor devices, the output power characteristics of the PV modules are determined by many factors such as the PV module status, external light intensity, ambient temperature, etc. When the PV modules are working, the output power decreases due to faults, light-induced degradation, reduction of the received light intensity because of shading or small illumination angle, increase of the working temperature of the PV modules in poor heat transfer conditions. As a result, the output power of one module decreases. Furthermore, the PV modules with low power generally cause the mismatch loss of the entire string and the energy generation of the overall PV plant is further reduced.

#### 2.2 Fault Types of PV Modules

PV modules degrade due to various external factors (UV, humidity, temperature, mechanical stress, and so on). The failure rate of PV modules shows a U-shape curve during the life cycle and is generally divided into three phases: infant, middle, and wear-out. The fault rate of PV modules varies in the entire running period, as shown in Figure 2.1.



Figure 2.1 Failure rate of PV modules in the entire life cycle

At the infant stage, faults of PV modules are usually caused by serious quality problems, such as fast degradation of module, crack, etc., which will cause the rapid decrease of output power of the PV modules. The performance of PV modules is typically stable in the middle period of operation and the performance degradation caused by faults is usually linear. PV module faults at the end of operation are usually caused by material aging. The impact on the output power of PV modules directly determines the operating life of the PV plant.

In practice, the typical faults of PV modules are the following, as is shown in Figure 2.2.



Figure 2.2 Fault types of PV modules

**Shattered glass**: Glass breakage due to quality or environmental causes such as bump by a flying granular. Shattered glass not only has impact on the output power of one module but also cause the mismatch loss of the string(s) containing this module. More important is the increased risk of safety because the isolation level decreases largely when the glass is broken. It is easy to cause electric shock in a rainy day or when water remains on the module surface. Therefore, when glass breakage happens to a module, please replace it as soon as possible in a safe way.

**EVA discoloration and delamination**: EVA failure due to EVA quality or the encapsulation process, which will lead to the decrease of incident light into the module and hence reduce the output power.

**Cell cracks**: Cell crack is the most common failure due to poor transportation or installation, which has very strong impact on the power output of a module. Such kind of modules should be replaced immediately. However, it is too difficult to find out all the modules with cell crack in the plant. Even for 0.1%, no inexpensive approach is available. Sometimes cell crack is not

obvious and is thus called hidden cracks. Both crack and hidden crack are of high risk for the entire plant because they can both lead to the hotspot and probably the firing of modules.

**Potential induced degradation (PID)**: Some PV modules in a PV system have a negative potential to earth and also have this negative potential to the earthed mounting system. Due to this potential difference, anode ion (generally  $Na^+$  ion) flows from the glass plate into the semiconductor material of the solar cell, and contaminate the cell. These  $Na^+$  ion have a strong negative influence on the performance of the PV cell (Polarization). As a result, solar cells become inactive and generate less electricity. One cause people are inclined to acknowledge is temperature & humidity. The degree of PID effects activity varies with the temperature & humidity level. Degradation is also related to the degree of contamination of the glass plate caused by objects that are electrically conductive, acidic, alkaline, or ionic. PID is the cancer of PV module and it must be avoided.

**Snail trails**: Snail trails is caused by the hidden crack which causes the oxidation of silver around hidden cracks. Snail trails may induce the rapid degradation of PV module.

**Metal corrosion**: Metal corrosion is the result of the oxidation of metal interconnection in a humid environment after the water invades into the module capsulation. As a result, the resistance of the module increases largely and the performance is reduced dramatically. Moreover, when this module is connected in the string, it causes the deleterious effect on the string performance by introducing mismatch.

**Backsheet chalking**: Backsheet chalking stems from the quality of backsheet that causes the invasion of water into module, which indicates probable PID and metal corrosion as a result.

**Hot spots**: When shading or non-uniformity occurs on one module, there is very high reversebias across a very small region, which causes high temperature and the so-called hotspot. When the hotspot lasts for a period, the breakdown of the solar cell encapsulated inside the module occurs, which probably leads to the fire.

#### 2.3 Introduction of On-site Inspection of PV Modules

There are several on-site approaches of inspecting and testing the PV modules that can directly test the modules in the PV plant without carrying these modules to laboratory.

#### Visual inspection

By means of visual inspection, glass breakage and disconnection of one string can be found out and then recovered. However, the quantity of modules is too large for O&M people to inspect. Therefore, this method is typically for occasional use.

#### Thermal image

Thermal image is the approach to detect some internal faults of PV modules by means of infrared camera. Hotspot and diode short-circuit are the most common faults that can be detected by thermal image. But thermal image is unable to detect other faults or failures like abnormal degradation and mismatch. This method is also for occasional use for the similar reason of visual inspection.

Recently, technologies combining visual inspection, thermal image and drone have been developed to be automatic approach for the inspection, which is believe to the future of O&M.

#### I-V curve

I-V curve is one of the effective approaches that can detect the electrical faults of one module or string. Any electrical abnormal can be recognized through I-V curve. Recently, more and more investors and developers are requiring I-V curve testing to be conducted during the commissioning of plants in order to assess the overall health of the plant from the beginning. For traditional I-V curve testing, specific equipment is required for offline testing. The procedure is shown in Figure 2.3. In practice, 0.1%-10% of the modules and/or 5%-50% of strings will be selected for testing by random. Two professionals firstly shut down the inverter/DC box, disconnect the target module/string by unplugging the terminals, connect the module/string to the device, operate the device, record the results and reconnect the module/string to the inverter/DC box. Professionals do the analysis afterward and output the diagnosis report. Typically, 1MWp plant with 1% module sampling or 10% string sampling needs 1~2 man-days to output the report, which is indeed dependent on the plant size and plant type.

The disadvantages of this traditional approach is low sampling rate, poor data quality due to uncertainty of testing, inconvenience and high safety risk for rooftop, mountain and lake plants and high cost for labors. Additional risk relies on the unplug action of the strings from inverter before traditional I-V testing, which will probably cause terminal damage and bring in high risk of arc.



Figure 2.3 Traditional offline I-V test

#### **Electroluminescence (EL)**

EL means PV module under exitation can emit near-band infrared light. With the help of highresolution IR camera, EL can help detect module quality issues such as cracks, PID and diode issues. In practice, EL is carried out at night to avoid interference of visible light and a power source is required for EL to exite one PV module/string, with the infrared images outputed in Figure 2.4.

Tradition on-site EL requires two professionals, EL camera, very heavy portable power bank and some accessories. Typically, 1MWp plant with 1% module sampling needs >2 man-days to output the report. Therefore, the disadvantages of traditional EL is similar to that of I-V curve.



Figure 2.4 EL test

To summerize, the state-of-art inspection methods, including visual inspection, thermal image, I-V curve and EL, all have the disadvantages of inconvenience and high cost due to repetitive testing in order to identify the exact location and root cause relating to panel faults. The cost-effectiveness of these methods should be estimated case by case in order to determine whether one or several of these methods are needed.



Huawei Smart I-V Curve Diagnosis

In 2016, as a result of joint innovation with Huanghe Hydropower Company (one subsidiary company of State Power Investment Corporation), Huawei released Smart I-V Curve Diagnosis online, which then became the hot sale in the market. In the past four years, this feature has evolved from version 1.0 to version 3.0 and has been sold by around 5GW around world. In 2020, version 4.0 will be released with more advanced and customized functions and most inverters released after 2016 support update to the latest version (For details, please refer to Huawei sales team).

In this chapter, a dedicated description will be aiming to demonstrate the mechanism and the function of Huawei Smart I-V Curve Diagnosis.

#### 3.1 Mechanism

#### 3.1.1 Mechanism for String I-V Scanning

String I-V Curve scanning with high-precision can be achieved through high-precision signal sampling and voltage/current controlling during fast scanning. After receiving the command of I-V scanning, the inverter(s) will





Figure 3.1 MPPT at the open-circuit point

(2) Reduce the string voltage linearly and collect voltage and current values simultaneously, as is shown in Figure 3.2.



Figure 3.2 Status during voltage decreasing

(3) Repeat voltage decreasing and data collecting until V is close to 0 (not equal to 0) for a whole I-V curve and the corresponding data, as is shown in Figure 3.3.



Figure 3.3 Status when voltage is close to 0

(4) Above is the reverse string scanning, after which there will be a forward scanning from the point close to short-circuit to the point of open-circuit, in order to increase the precision of data. This is because there is capacitor effect during the scanning and the combination of reverse and forward scannings can eliminate this negative effect by data governance.

#### 3.1.2 Mechanism for Diagnosis

The Diagnosis is carried out based on the assumption that most of the PV modules are unlikely to have one particular fault. Therefore, the "true" irradiance and module temperature for the solar cells encapsulated in the module can be calculated according to the effective data collected during I-V curve scanning and uploaded to Huawei management system, which will then compare the data with built-in physical models and judge whether there is fault or not in the strings through mode recognition with the trained AI model built in.

Any type of faults related to electrical performance has their unique signals. After translating string I-V curve features to characteristics, it is easy to determine whether strings are abnormal and the causes behind them.



Example 1: string I-V curve will introduce notches when there is current mismatch, as is show in Figure 3.4.

Figure 3.4 Typical I-V curve for strings with current mismatch

Example 2: If one or more modules are shaded, the I-V curves change a lot with obvious power reduction at the high voltage range, as is shown in Figure 3.5.



Figure 3.5 Typical I-V curve for strings with one or more units in shadow.

#### **3.2 Solution of Smart I-V Curve Diagnosis**

The solution of Smart I-V Curve Diagnosis comprises the data collection at inverter side, data transportation through SmartLogger and diagnosis integrated in Huawei management system, which follows the standard device-pipe-cloud topology. As is shown in Figure 3.6,

1) Device: Inverter (SUN2000/SUN2000HA\*) with a license for Smart I-V Curve Diagnosis

Inverter receives the command of scanning, implement the command, collect I-V data and send them to SmartLogger.

\*Inverters released after 2016 typically support Smart I-V Curve Diagnosis while older inverters fail to be upgraded.

2) Pipe: SmartLogger (SmartLogger1000/SmartLogger2000/SmartLogger3000)

SmartLogger receives commands from management system, dispatch them to inverters and then receives the data collected by inverters and uploads the data to management system.

3) Cloud: Huawei management system (NetEco 1000S or the coming FusionSolar 7.0)

Huawei management system is the platform where the plant-level, array-level or inverter-level diagnosis starts. In the management system, one can fill in and modify the parameters for I-V curve scanning. After one-click, the management system can output the diagnosis results with fault statistics and original I-V data.



Figure 3.6 Typical I-V curve for strings with one or more units in shadow.

#### **3.3 Specifications of Smart I-V Curve Diagnosis**

To achieve high presion diagnosis without the assist of external meters, Smart I-V Curve Diagnosis has some technical requirements.

- 1) Illumination: Stable illumination >400W/m<sup>2</sup> is the minimal requiement for I-V scanning. The higher the illumination, the better the data quality.
- Accuracy of data: Smart I-V Curve Diagnosis is developed based on the machine learning, the fundamental of which is the quality of data. This indicates that the sensors should be of high accuracy.
- 3) Scan speed: The I-V data should be obtained in a steady condition and is typically interfered by atmosphere variation, such as wind and sunlight. The only option for on-site testing is to create a quasi-steady state for scan during a very short period to avoid environment variation. Therefore, the scan speed should be very fast. Besides, condiering the capacitor effect of high-efficiency modules, the scan speed should be no less than 100 ms.
- 4) Synchronization: Since the diagnosis after scanning requires string-string comparisons, synchronization of string scanning can ensure the comparability of I-V curves.
- 5) Resolution: Data points for one I-V curve is no less than 100 to keep the I-V curve as smooth as possible.
- 6) Experience: In the diagnosis report, the faulted string and the cause of fault should be

clearly denoted.

Based on these requirements, Huawei developed its Smart I-V Curve Diagnosis, whose specifications are listed in Table 3.1. To enhance the experience, Smart I-V Curve Diagnosisis is designed to complete the scan and diagnosis within 15 min for a 100MW plant. Moreover, the compatibility of I-V scanning is improved to deal with complex cases such as bifacial module, Y-connector, reservation, etc.

Items	Specifications		
	<1s for one scan for one string		
Scan speed	<25s for one 185KTL inverter (9 MPPT)		
	<15min for 100 MW		
Scan resolution	128 points		
Scan accuracy	Voltage/Current ≤0.5%		
Scan convenience	Online operation and one-click for a plant		
Scan consistency	>200 strings at the same time (If total string number is >200)		
Scan footprint	All selected strings		
Analysis & Report	Automatic analysis and fault confirmation report		
Energy loss	$\approx 0 \mathrm{kWh}$		
Compatibility to modules	All, including bifacial, Shingle, Half-cell, etc.		
Others	Y-connector compatible, reservation for diagnosis, O&M advisor, etc.		

Table 3.1 Specifications of Smart I-V Curve Diagnosis

#### **3.4 Output of Smart I-V Curve Diagnosis**

There are *four* output documents after diagnosis: *detection report*, *diagnostic report*, *O&M report* and *original data*. As is shown in Table 3.2, Smart I-V Curve Diagnosis can recognize 14 kinds of faults and possible fault causes, which are verified by TUV.

Table 3.2 Faults a	nd possible causes	in diagnostic rep	ort
--------------------	--------------------	-------------------	-----

No.	Fault	Possible causes of failure
1	PV string open circuit	PV string breakage/PV string configured by mistake
2	Current mismatch in the PV string	Shade/dust/PV module current inconsistent
3	Abnormal PV module output current	Shade/glass breakage/hidden crack
4	Abnormal BV string voltage	Diode short circuit/PV module invalid/PV module
4	Abhormar i v string voltage	quantity incorrect
5	Low PV string short-circuit current	Abnormal orientation/dust/PV module degradation
6	Low PV string power	Abnormal orientation/dust/PV module degradation
7	No string connected	Check whether PV strings are connected to the inverter
Q	Missing configurations of DV strings	Check whether string information is configured in the
0	wissing configurations of PV stilligs	system
9	Excessively low irradiance	The solar radiation is insufficient

		(Analyzed the data sent by HW inverter)
10	Slight current mismatch in the PV string	Dust/slight shade/glass breakage
11	Excessively low PV string parallel resistance	PID degradation/dust/uneven PV module irradiance
12	Excessively high PV string series resistance	High cable resistance/abnormal internal resistance of the PV module
13	Abnormal curve near MPP in the PV string	Hotspot/hidden crack/glass breakage
14	Scanning data invalid	Irradiation cause

The O&M report provides the exact location of strings with faults inlcuding suggestions for the customers to assess and confirm the faults.

All the above faults should be fixed but there should be priority for faults causing system risk and/or higher yield loss. In Table 3.3, the impacts of faults on yield and system security are demonstrated, which are referred to give O&M suggestions in Huawei management system. For example, if "Abnormal PV module output current" occurs in diagnosis report, the cause with the highest possibility is breakage of glass. Since this can take O&M in risk, the suggested O&M strategy will be "replace the module". If "Slight current mismatch in string" occurs, take it as minority issues and just keep on watching the evolution of such faults.

Fault Type	Impact on Yield	DC security risk	Possibility of occurrence
PV string open circuit	100% for each string	Risk of electric shock in O&M	High
Current mismatch in string (Dust)	3-30% for each string	Severe blockage causes hotspot risks and modules reliability degrades	High
Abnormal PV module output current (Breakage)	>5% for each string	Energy yield loss, modules reliability risks, and safety risk in O&M	Very High
Current mismatch in string (Shade)	1-5% for each string	Same with the dust	Very High
Slight current mismatch in string (Slight shade)	1-4% for each string	Maybe there is dust, shade or other problems	Very High
String connection reverse	100% for each string	Risk of electric shock in O&M	Very Low
Low PV string power(PV module degradation)	3-7% for the whole plant	Module reliability degrades	Inevitable
Abnormal PV string voltage(Diode short circuit)	~1.1-1.5% for each string	Module reliability degrades	High
Abnormal PV string voltage (PV module invalid)	0.5-0.7% for each string	The string information may not be configured successfully in system	Very Low
Low PV string power (Abnormal orientation)	0.5-0.7% for each string	Inherent problems in PV plant design and cause energy yield loss	Very Low
Excessively low PV string parallel resistance (PID)	5-50% for the whole plant	Affecting the service life of the modules.	High temperature, humidity& salinity Scenario
Abnormal curve near MPP (Hotspot)	0.01% for each module hotspot	Risk of fire, accelerating aging, etc.	Very High
Excessively high PV string series resistance (High cable resistance)	0.5-5% for the whole plant	Fire risk caused by DC arcing	Low
Abnormal PV module output current (Hidden crack)	Uncertain	Hot spot risks that degrade reliability	Very High

Table 3.3 Faults and their impacts

# **4** How to Use Smart I-V Curve Diagnosis

This chapter is devoted to description on how to operate Smart I-V Curve Diagnosis and how to read diagnosis report and make O&M Decision, which will take one reference plant in Asia as example.

#### 4.1 Start the Diagnosis and Output the Reports

#### 4.1.1 **Requirements**

All of the following conditions should be met to ensure normal PV string diagnosis; otherwise, scanning will fail or misdiagnosis may occur.

- The license for Smart I-V Curve Diagnosis is valid. Otherwise, one can ask for help from Huawei engineer team. For details, see the *Smart I-V Curve Diagnosis User Manual*.
- The day is sunny with stable sunlight. The irradiance is  $> 400 \text{ W/m}^2$ .
- The cleaning status is consistent for a diagnosis task.
- The PV modules are clean and dry. Recommended: start the function after PV modules are cleaned or heavy rain has stopped.
- The PV modules connected to the same inverter have identical type and model. Every PV string has the same number of PV modules connected in series.

#### 4.1.2 **Operation**

This part can refer to Chapter 4 of *Smart I-V Curve Diagnosis Technical White Paper*. Please ask Huawei sales team for this material.

### 4.2 Review of Diagnostic Report and Make an Informed O&M Decision

As is shown in Figure 4.1, there are four documents as output of Smart I-V Curve Diagnosis, Detection report, Diagnosis report, O&M report and original data spread sheet.

**Detection report** contains the plant information, evaluation of the PV string failure rate and fault type analysis.

**Diagnostic report** contains information of scanning task, overview on diagnosis, PV string I-V curve details and PV string performance data details.

**O&M report** contains information of task, overview on diagnosis and following advice on maintenance.



Figure 4.1 Output of Smart I-V Curve Diagnosis



Figure 4.2 Statistics in Detection report

In practice, Detection report, as is shown in Figure 4.2, is used as a summary of the state of health at the DC side in a PV plant, which might be useful for asset management. O&M report is the guide for O&M people to confirm the faults mentioned in the report and recover the faults. For further information, one can turn to Diagnosis report and original data spread sheet which include more details such as I-V curve of each string with 128 points, STC performance of each string that is translated from raw data, etc. For routine O&M, 3-4 times/year is suggested. The function of reservation for Smart I-V Curve Diagnosis is preferred for 0-touch experience, which can provide an automatic output of diagnosis report.

For advanced application, one can compare the string STC performance to the theoretical value to investigate the degradation behavior of modules, which may serve as the guide for plant design in the future. Otherwise, the STC performance can be used to study the real-time soiling performance when there is a clean reference, which is helpful to guide the strategy for routine cleaning.

In Smart I-V Curve Diagnosis 4.0, there will be function update called "O&M advisor". All the faults will be sorted by their urgency and impact on yield loss and thus given the priority for recovery, as is described in Chapter 3. O&M people can make their decisions based on this reference.

#### 4.3 Case Study

Plant size: 50MW

Plant location: Southeast Asia

Plant introduction: Mountain, complex terrain and difficult O&M.



Figure 4.3 Top view of the PV plant for Smart I-V Curve Diagnosis



Figure 4.4 Diagnosis report of the abovementioned PV plant

After inspection with Huawei Smart I-V Curve Diagnosis, Figure 4.4 shows the diagnosis report shows 3960 strings were scanned and 188 faulted strings were found, with fault rate 4.7%. The top three faults are "PV string open circuit", "PV module output current abnormal" and "Abnormal curve near MPP in the PV string".

martle	ogger01 PV strin	ng O&M report							
. Inf	formation of Tas	k							
nak ze	180	CASE2 Plant 498				Creation Time	2018-12-22 12:	17:32	
losnin	eening status Uncleaned					Task type	PV plant level	diagoosis	
otal s	number of strings	392				Number of faulty strings	22		
rredie	anco (T/II')	967.15(Predicti	re value)			Temperature Of Panel ('C)	64.62(Prediction	re value)	
. Ove	rview on Diagno	sis							
NO.	Inverter	Inverter (SN)	String	Yoc[Y]	Isc[A]	Dafective type		Locate	Position of Fealty PV Module
1	10201	X01073024/11490000X	118	-	·	W string open circuit () string bry configured by mistake	akage/W string		
2	11402	XXXX73826678489000X	116	802.70	9.37	PV module output current annormal breakago/hidden crack) PV string open circuit (PV string bro	ukage/PV string		
,	11901	XXXX73024671499000XX	118	-		configured by mistake PV module output current abnormal	(shade/glass		
5			113	806, 50	2.01	breakage/hidden crack) PV module output current abnormal	(shade/glass		
6	10801	X033X738246714660133X	197	806.20	9.40	PV module output current abnormal brookene/hidden crack	(shade/glass		
7		10111730246788001333	PV1	805, 30	8.94	PV module output current abnormal breakage/hidden crack)	(shade/glass		
8	10901	Addition of the owned of the ow	P12	805, 30	8.94	Current mismatch in the PV string module current inconsiste	shade/dust/PV nt)		
9		X03X7302001E901XXX	197		-	PV string open circuit (PV string bry configured by mistake)	akage/PV string		
10	10102		P\$8	-	-	PV string open circuit (PV string bro configured by mistake	akage/PV string		
11	11602	X033X7302467H990133X	112	810, 80	8, 51	Ahnormal curve near MPP in the Onotspot/hidden crack/glass b	PV string reakage)		
12	-		112	821.50	8.59	PV module output current abnormal breakage/hidden crack)	(shade/glass		
13	-		P13	•	·	enfigured by mistake	akage/PV string		
14	11901	ALCONTRACTOR	114	811.70	8.83	PV module cutput current abnormal PV module cutput current abnormal	(shado/glass		
15	-		115	819, 10	8.52	breakage/hidden crack PV module output current abnormal	(shado/glass		
17			112	807.50	8.72	breakage/hidden crack) PV module output current abnormal	(shado/glass		
18	11601	01 X000373024/THE90200X		809.20	8.86	PV module output current abnormal brooksmo/bidden crack)	(shado/glass		
19	12101	XXXX730266788901XXX	P18	-	•	PV string open circuit (PV string breakage/PV string configured by mistake)			
20	12002	XXXXX73024671489013XX	192	782.00	8.65	PV string voltage absormal (diode al module invulid/PV module quantity	ort circuit/W incorrect)		
21	12002		197	791.50	8, 70	PV string voltage abnormal (diode al module invalid/PV module quantity	ort circuit/W incorrect)		
22	12102	XXXX7382447 (HOOKXXX	P01	820.30	8.78	PV module output current abnormal breakage/hidden crack)	(shade/glass		
. Fol	lowing advise								
NO.		Description				Following	advise		
1	PV string open circu confi	ait (PF string breekag igared by mistake)	e/PV strie	step 1: Step 2: between within Step 3: inverte Step 4:	Stop 1: Bock if the strings are connected correctly, if connections are loss, or not connected. Stop 2: If the strings are connected to inverte, these strict of the instrumer and pall off the connector between strings and inverter then assumer 'Not of the strings with a millimeter and thek whether the 'Doc is Stop 2: If the iso is within correct grantmenter, then deck whether the connector between string and inverter is breaks, if eventhag is al, then check if there is break circuit inside of inverter. Stop 2: If the loss is advanced, then check if there is breaken circuit inside of inverter.				
2	PF module cutput break	current abnormal (da inge/hidden crack)	do/glass	Step 1: Step 2: panol, i Step 3: measure Step 4: clean 1 Step 5: the abe	So p: 1 sources the W string for label. If there is hade, clinicas the hade and meaner again. So p: 1 there is no hade an apach click if there are forcing matters at first the harder of the p: 1 there is no hades an apach click if there are forcing matters at first the hade of the source again a force product at the america of participate shade. If there is brain glass, if we planse means a string the product at the america of participate shade. If there is brain glass, if we planse means a string the product at the america of participate shade. If the string has been classed. If not, close, the P string and the assess equivalent for P multiple surface is any close, the P string and the masses equivalent for the P multiple surface is any the amorganism of the string and the masses and the rest and given in the string the hand langer to locate the amorganism of the string and the masses and the string is not force themail langer to locate the amorganism of the string and the masses and the string the string is not force themail langer to lands the amorganism of the string and the masses and the string the string is not force themail langer to lands the amorganism of the string and the masses and the string and the string is not force themail langer to lands the amorganism of the string and the string and the string is not force themail langer to lands the string and the string the string and the string is not force themail langer to lands the string and the				
3 Carrent minmatch in the PV string (shads/dust/PV module current incensistent)			Step 1: changes Step 2: Step 3: Step 4: aodule Step 5: tee 5:	Disp. If there is no finit, plasse identify the model with decommit current by If tester. Step 1: Final etc. (if the scanning is done at a sums $\phi_0$ correct instants the source when the irradiance Step 2: Schnei if there is advance, if yas, plasas measure again after reaseing the shades. Step 2: If the PT etric has not been closed. Step 2: If the PT etric has not been closed.					
4	Absormal curve Øsotspot/hid	e near MPP in the PV s den cruck/glass break	tring ugo)	Step 1: curve b Step 2: Step 3: module Step 4: Step 5: output	Leaving one proc. See [17] Financiac tack, if the scan was done in a summy day, the rapid charge of irradiance may induce IV (rapper) (rapped) (				
5	PV string voltage a module invalid/5	abnormal (diode short W module quantity inc	circuit/Pi orrect)	Step 1: Step 2: box. 18 Step 3: broken Step 4: the vol tempere	Check whe Observe w no, repla If none o ribbon for If there tage of th sture of pe	ther the number of FV modules consecte bether there are traces of burning at ce the PV module with the name model. if the above stists, please use IR came interconnection. is no abovemal found on the module with estrings (from same MFPI), to see if estrings to check whether there	to the PV strin the interconnecti ra to check if th i IR comera, plea it is too low.And is abnormal tempe	g is correct. on strip, bac ere is short se use voltag if yes, plea rature distri	kaheet, and wiring circuited diade or e meter to check th se measure the bution.

Figure 4.5 O&M report of the abovementioned PV plant

After reviewing the diagnosis report, one copy of O&M report was taken with O&M engineers to confirm the faults on site.

Following the string number and instruments in O&M, engineers easily found out the faulted string and then verified the faulted module by infrared camera. Figure 4.6 shows three typical examples that were verified after Smart I-V Curve Diagnosis, hotspot, diode short-circuit and shading. These three are all imperceptible faults at DC side but of high risk since the evolution of such faults can lead to the burning of faulted module and maybe spread the fire risk to the neighbored modules and devices. In some accidents we saw in Southeast Asia, the PV plant is built in grass-rich area and the fire starts from one module to a whole plant when it is dry season and the dry grass is not collected in time.



Figure 4.6 Cases of verification of the alarms from Smart I-V Curve Diagnosis

# **5** Value of Smart I-V Curve Diagnosis

From the above chapters, one can see that Smart IV Curve Diagnosis is one powerful tool to help the plant owner to manage the plant by providing valuable information such as identifying what and where possible problems are occurring at the plant and to provide the necessary steps in confirming the exact root cause of the problem. One key issue is to ascertain the exact value of this tool in order to helps us understand why we need Smart IV Curve Diagnosis and how to make best use of it.

#### 5.1 Secure PV Assets by 100% Inspection

Risk control is the topmost topic for PV plant investment. Each stage has its own risks, which are transferred to O&M after commission. From an ideal concept, the investors and developers should have the capability of accessing all the devices in the PV plant, knowing their state of health.

Unfortunately, in a traditional plant, there are obstacles in front. One is that there is no access of acquiring status of 100% devices from the DC side, which in fact processes the majority of the cost of an entire plant. As mentioned in Chapter 3, traditional inspection methods can only achieve partial inspection so that not all the faults can be detected and then recovered. Moreover, these inspection methods might bring in more risks like labor safety. Under such condition, DC side is not totally transparent and what one knows about the plant is incomplete. But one should make the balance of high cost and asset security when there is no efficient approach of 100% inspection on DC side. As a result, the security of assets is under risk. The other obstacle is about the data collected from the plant even if there are sensors on the DC side. These data are typically lack of accuracy, synchronization, comparability, etc. so that they typically helps little for the investors and developers.

By means of Smart I-V Curve Diagnosis from a 100% sampling perspective, it is possible to evaluate state of health of the entire plant at key stages.

- (1) 100% inspection after commission: Quality of the plant and fast defect elimination are two major concerns after commission. Traditional methods have no idea of 100% inspection on the DC side which actually brings risks. Smart I-V Curve Diagnosis helps 100% inspection on the DC side with detailed description on the faults, which provides solid evidence for the investors and developers to recall and solve the problems and thus reduce the risks on the assets.
- (2) 100% inspection for O&M: Smart I-V Curve Diagnosis provides string-level inspection for 100% device on the DC side and makes all the devices transparent and traceable to investors and developers, which is definitely helpful for decision making and risk controlling.

(3) Appropriate O&M strategy: whether one fault needs to be recovered is determined by the balance between the value brought by the recovery action and the cost for recovery, indicating that not all the faults are urgent to be recovered. Smart I-V Curve Diagnosis provides the methodology of evaluation of yield loss and system risk for the customers to help them make a right decision with higher ROE.

#### **5.2 Saving Energy Yield Loss by Protecting PV System from Faults**

As is described in Chapter 3, any faults in module may lead to the yield loss of energy, most of which can be approximately evaluated by Table 3.3.

Since each plant is independent and the details may vary a lot, it is not easy to evaluate the energy loss at the design stage or before 100% I-V curve inspection. However, a statistical method based on I-V curve data from a large quantity of PV plant may provide a reference value for energy loss.

From 2016-2019, Huawei together with the customers in China led joint innovation projects which have inspected a couple of plants with 1.2 GW capacity in China by means of Smart I-V Curve Diagnosis. These plants cover almost all the regions of China and are commissioned within 5 years. Table 5.1 shows the statistical analysis on all the failures. It can be seen that "PV module output current abnormal", "Current mismatch in the PV string" and "PV string voltage abnormal" are top three alarms and the possible causes are shade, glass breakage, diode short circuit, etc.

NO	Item	Failure rate	Weighted factor for one string	Yield loss
1	PV module output current abnormal (shade/glass breakage/hidden crack)	3.30%	5.00%	0.17%
2	Current mismatch in the PV string (shade/dust/PV module current inconsistent)	1.60%	3.00%	0.05%
3	PV string voltage abnormal (diode short circuit/PV module invalid/PV module quantity incorrect)	1.49%	1.80%	0.03%
4	PV string open circuit (PV string breakage/PV string configured by mistake)	1.04%	100.00%	1.04%
5	Slight current mismatch in the PV string (dust/slight shade/glass breakage)	0.95%	1.00%	0.01%
6	Abnormal curve near MPP in the PV string (hotspot/hidden crack/glass breakage)	0.57%	0.00%	0.00%
Total ir	n percentage	8.95%	NA	1.29%

Table 5.1 Statistics on the string faults all over the 1.2 GW PV plants

When weighted factors for one string are endowed to specific faults, the approximate yield loss from all faults can be written as:

$$Loss\% = \sum_{i=1}^{6} P_i * WF_i$$

Where  $P_i$  is the possibility of the fault in No i,  $WF_i$  is the weighted factor for one string for fault in No i.

As a result, Loss%=1.29% and the approximate economic loss can be written as:

Economic Loss=
$$\sum_{i=1}^{T} \frac{PPA_i *Loss\% *Yield_i}{(1+r)^i}$$

Where  $PPA_i$  is the electricity price of year i, T is the total period of electricity purchase, r is the discount rate.

#### 5.3 Saving Time and Cost Compared to Other Approaches

To achieve 100% inspection on the DC side, the only way is traditional I-V testing with 100% sampling. In a 400MWp/300MWac PV plant in the desert of Middle East, this test was mandatorily taken in December, 2019, which is taken in the comparison in this section.

Table 5.2 Comparison between Smart I-V Curve Diagnosis and traditional I-V testing.

For 400MWp	Traditional I-V Testing	Smart I-V Curve Diagnosis	
Tools Cost	~\$12000-\$25000/set * 4 sets (Instruments & software price varies from vendors.)	Only software	
Time for Inspection	40 Days	25 Min in total	
Time for Analysis	7 Days		
Yields Loss	~200MWh in MEA (Inverter turning off when testing)	Almost 0	
Labor	12 extra professionals for testing 2 extra professionals for analysis	Only O&M staff	

As is listed in Table 5.2, it can be seen that traditional I-V testing should pay for the tool cost, the man-days for inspection and analysis and the electricity price loss due to yield loss caused by inverter turning off during the testing. For Huawei, Smart I-V Curve Diagnosis needs only one click by O&M staff.

Total cost difference for large scale utility plant should be expressed by the following equation:

 $\Delta Cost = (N*T+(40*12+7*2)*S+Y_{Loss}*PPA)*R$ 

Where N the set number of tools, T the price of one set of tool, S salary per man-day for professionals,  $Y_{Loss}$  the yield loss during testing, PPA the price for 1kWh electricity generated by PV plant, R the sampling ratio.

Case 1: When it refers to the 400MWp/300MWac ME plant with 100% sampling,  $\Delta Cost=100,400$ , or  $\Delta Cost=251/MWp$ , assuming PPA=0.024/kWh, S=100/man day.

Case 2: If one 3<sup>rd</sup> party organization is required to provide the I-V curve testing service, with 30% sampling,  $\Delta$ Cost=\$121,260, or  $\Delta$ Cost=\$303/MWp, assuming PPA=\$0.045/kWh, S=\$800/man day and no expense for tools. If 100% inspection is required,  $\Delta$ Cost will increase to ~\$900/MWp.

Assuming one I-V inspection per year,  $\Delta$ Cost of the 30-year lifecycle will be ~\$12388/MWp with discount rate as 6%.

Two more things must be pointed out are:

(1) Traditional I-V testing has high uncertainty of testing. The synchronization of data is not as good as that from Smart I-V Curve Diagnosis. One major issue is that the soiling level may be different when time elapses, which may lead to the poor comparability of data.

(2) It is required to unplug the strings from inverter before traditional I-V testing, which will probably cause terminal damage and bring in high risk of arc. According to our previous studies, the failure rate of module terminals after unplugging is around 8%, which is 10 times higher than that is as factory.

# **6** Appendix

### 6.1 Third-Party Authentications



Figure 6.1 Third party's precision authentication report

www.tuv.com	Page 2 of	48	Report no.: 15098807 002	www.tuv.com	Page 3 of 48	Report no.: 1	5098807 00
Project Description							
ower Plant Holder	Huanghe Hydropower De	evelopment Co	., Ltd.	Test Result	Fault description	Remark	Result
ceptance Location	Huanghe Longyangxia Hy	ydropower&So	olar energy Power Plant	No output	No output in a string due to	See below test result	P
ceptance Producta	Huawei Intelligent PV arra	ay Managemer	nt Function	Soiling	cell's disconconnection More than ¼ areas of 2 cells	See below test result	Р
lafe etta.	Huawei Intelligent PV arra (Version: FusionSolar Intellig	ay Managemer jent PV array Man	nt Function System agement Function System V100R003)	High series resistance (Rs)	Series resistance increased more than 5Ω in a string	See below test result	Р
tem informations	SUN2000-40KTL-NOC			Potential induced degradation (PID)	More than 4 cells in a string have PID caused power degradation (>20%)	See below test result	Р
wer Plant Capacity	850MW			Cell Shadowed	More than 1 cell was shadowed in a string.	See below test result	Ρ
sting Laboratory	TÜV Rheinland (Shangha	ii) Co., Ltd.		Current mismatch	Short-circuit current of cells mismatch in a string	See below test result	Ρ
t Report No.1	15098807 002			Low current output	More than one cell have no output current in a string	See below test result	P
er No.a	154162322			Front glass breakage	More than one cell's front glass were broken in a string	See below test result	Ρ
t Basult Decerie	diam:			Cell output current abnormal	More than one cell in a string output current abnormal	See below test result	P
cording to the technica	al requirements provided by H element Function tested by T	Huawei Techno TÜV Rheinland	logies Co., Ltd., after Huawei (Shanghai) Co., Ltd in Huanghe	Cracked cells	More than one cell cracked in a string cause more than 50% power loss	See below test result	Р
ngyangxia Hydropowe awei Intelligent PV a	r&Solar energy Power Plant.	The result is:	meet the requirements of the	Bypass diode short- circuit	More than one defective bypass diode short-circuit in a string	See below test result	Р
chnical requirements	. The detail test results are	as follow test	report.	Broken cell interconnect	More than one cell interconnect broken in a string	See below test result	Ρ
gnature				E Lower short-circuit	The short-circuit current lower	See below test result	Р
sted by : John Dai	F	Reviewed by : '	Fobias Yang	Rapid power degraduation	MPPT power lower than 90% normal value in a string	See below test result	Р
gnature : John	Dai	Signature :	Cham	Note: PV module failure	s refer to attachment <review f<="" of="" td=""><td>ailures of Photovoltaic Mo</td><td>dules&gt;.</td></review>	ailures of Photovoltaic Mo	dules>.
ate : 2016.05.13	C	Date : 2016.05.	13	T pee V3			

Figure 6.2 Third party's function authentication report